## VS-ETX1506-M3

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# Hyperfast Rectifier, 15 A FRED Pt<sup>®</sup>



PRIMARY CHARACTERISTICS							
I <sub>F(AV)</sub>	15 A						
V <sub>R</sub>	600 V						
V <sub>F</sub> at I <sub>F</sub>	1.55 V						
t <sub>rr</sub> (typ.)	18 ns						
T <sub>J</sub> max.	175 °C						
Package	TO-220AC 2L						
Circuit configuration	Single						

#### **FEATURES**

- Hyperfast recovery time, extremely low Qrr
- · Low forward voltage drop
- 175 °C operating junction temperature
- · Low leakage current
- True 2 pin package
- Designed and qualified according to JEDEC<sup>®</sup>-JESD 47
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

#### **DESCRIPTION / APPLICATIONS**

State of the art hyperfast recovery rectifiers designed with optimized performance of forward voltage drop, hyperfast recovery time, and soft recovery.

The planar structure and the platinum doped life time control guarantee the best overall performance, ruggedness and reliability characteristics.

These devices are intended for use in PFC boost stage in the AC/DC section of SMPS, inverters or as freewheeling diodes.

The extremely optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

ABSOLUTE MAXIMUM RATINGS										
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS						
Peak repetitive reverse voltage	V <sub>RRM</sub>		600	V						
Average rectified forward current in DC	I <sub>F(AV)</sub>	T <sub>C</sub> = 141 °C	15	۸						
Non-repetitive peak surge current	I <sub>FSM</sub>	T <sub>J</sub> = 25 °C	120	A						
Operating junction and storage temperatures	T <sub>J</sub> , T <sub>Stg</sub>		-65 to +175	°C						

<b>ELECTRICAL SPECIFICATIONS</b> ( $T_J = 25 \text{ °C}$ unless otherwise specified)								
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS		
Breakdown voltage, blocking voltage	V <sub>BR</sub> , V <sub>R</sub>	I <sub>R</sub> = 100 μA	600	-	-			
Forward voltage	VF	I <sub>F</sub> = 15 A - 2		2.5	3.4	V		
	۷F	I <sub>F</sub> = 15 A, T <sub>J</sub> = 150 °C	-	1.55	2			
		$V_{R} = V_{R}$ rated	-	0.02	36			
Reverse leakage current	I <sub>R</sub>	$T_J = 150 \text{ °C}, V_R = V_R \text{ rated}$	-	40	250	μΑ		
Junction capacitance	CT	V <sub>R</sub> = 600 V	-	12	-	pF		
Series inductance	L <sub>S</sub>	Measured lead to lead 5 mm from package body	-	8	-	nH		

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RoHS COMPLIANT

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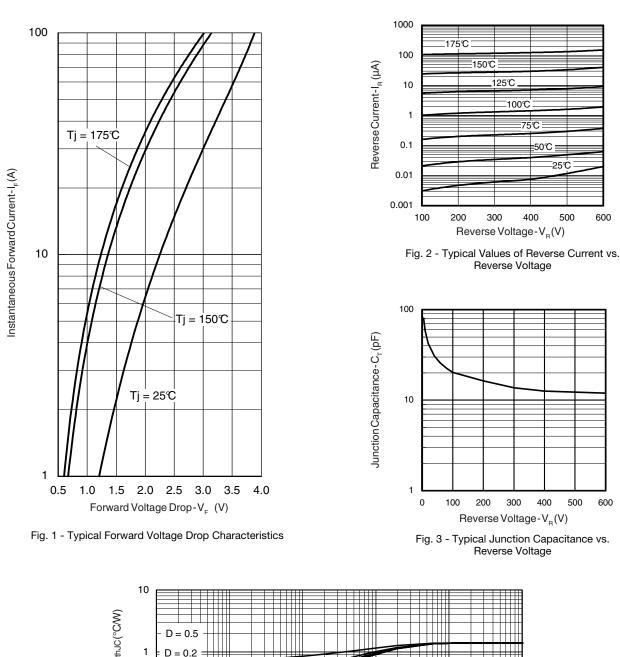
<b>DYNAMIC RECOVERY CHARACTERISTICS</b> (T <sub>J</sub> = 25 $^{\circ}$ C unless otherwise specified)								
PARAMETER	SYMBOL	TEST CO	NDITIONS	MIN.	TYP.	MAX.	UNITS	
		$I_F = 1 \text{ A}, \text{ d}I_F/\text{d}t = 100$	) A/µs, V <sub>R</sub> = 30 V	-	17	23		
Reverse receiver time	+	$I_F = 15 \text{ A}, \text{ d}I_F/\text{d}t = 10$	00 A/µs, V <sub>R</sub> = 30 V	-	18	30	50	
Reverse recovery time	t <sub>rr</sub>	T <sub>J</sub> = 25 °C		-	20	-	ns	
		T <sub>J</sub> = 125 °C	I <sub>F</sub> = 15 A, dI <sub>F</sub> /dt = 200 A/µs, V <sub>R</sub> = 390 V	-	45	-		
Poole rocovery ourrent		T <sub>J</sub> = 25 °C		-	2.7	-	A	
Peak recovery current	I <sub>RRM</sub>	T <sub>J</sub> = 125 °C		-	5.5	-		
	0	T <sub>J</sub> = 25 °C		-	26	-	nC	
Reverse recovery charge	Q <sub>rr</sub>	T <sub>J</sub> = 125 °C		-	130	-		
Reverse recovery time	t <sub>rr</sub>		l <sub>F</sub> = 15 A,	-	32	-	ns	
Peak recovery current	I <sub>RRM</sub>	T <sub>J</sub> = 125 °C	dI <sub>F</sub> /dt = 800 A/µs,	-	17	-	А	
Reverse recovery charge	Q <sub>rr</sub>		V <sub>R</sub> = 390 V	-	290	-	nC	

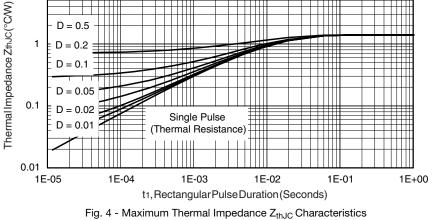
THERMAL - MECHANICAL SPECIFICATIONS									
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS			
Maximum junction and storage temperature range	T <sub>J</sub> , T <sub>Stg</sub>		-65	-	175	°C			
Thermal resistance,			-	1.2	1.4				
junction-to-case	R <sub>thJC</sub>		-	3.7	4.3				
Thermal resistance, junction to ambient	R <sub>thJA</sub>	Typical socket mount	-	-	70	°C/W			
Typical thermal resistance, case to heatsink	R <sub>thCS</sub>	Mounting surface, flat, smooth, and greased	-	0.5	-				
Weight			-	2	-	g			
weight			-	0.07	-	oz.			
Mounting torque			6 (5)	-	12 (10)	kgf · cm (lbf · in)			
Marking device		Case style TO-220AC 2L		ETX	1506				

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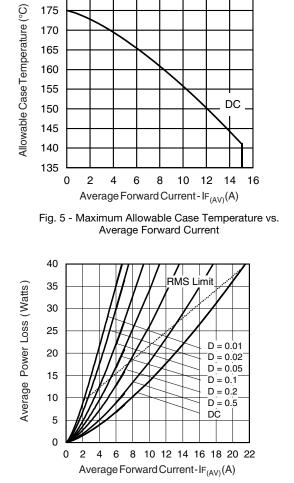
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Fig. 6 - Forward Power Loss Characteristics

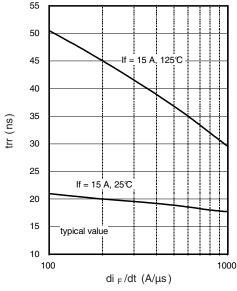


Fig. 7 - Typical Reverse Recovery vs. dl<sub>F</sub>/dt

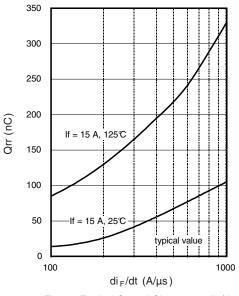


Fig. 8 - Typical Stored Charge vs.  $dI_F/dt$ 

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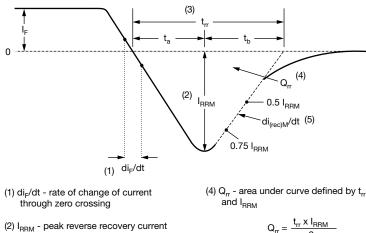
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 $Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$ 

(3)  $t_{rr}$  - reverse recovery time measured from zero crossing point of negative going  $I_F$  to point where a line passing through 0.75  $I_{RRM}$  and 0.50  $I_{RRM}$ extrapolated to zero current.

(5)  $di_{(rec)M}/dt$  - peak rate of change of current during  $t_b$  portion of  $t_{rr}$ 

Fig. 9 - Reverse Recovery Waveform and Definitions

#### **ORDERING INFORMATION TABLE**

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Device code	VS-	E	т	x	15	06	-МЗ
L	1	2	3	4	5	6	7
	1 - 2 - 3 - 4 - 5 - 6 -	E = T = X = Cur Volt	cuit conf single 2L TO-2 hyperfa rent coo	de: 15 = de: 06 =	n: very time 15 A 600 V		
Ľ	7 -			ntal digit gen-free		-compli	iant, an

ORDERING INFORMATION (Example)							
PREFERRED P/N	BASE QUANTITY	PACKAGING DESCRIPTION					
VS-ETX1506-M3	50	Antistatic plastic tubes					

LINKS TO RELATED DOCUMENTS						
Dimensions	www.vishay.com/doc?96156					
Part marking information	www.vishay.com/doc?95391					

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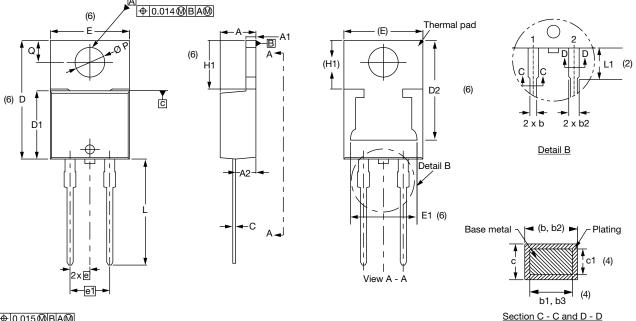
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### **TO-220AC 2L**

#### **DIMENSIONS** in millimeters and inches

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⊕0.015@BA@



SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STMBOL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.25	4.65	0.167	0.183	
A1	1.14	1.40	0.045	0.055	
A2	2.50	2.92	0.098	0.115	
b	0.69	1.01	0.027	0.040	
b1	0.38	0.97	0.015	0.038	4
b2	1.20	1.73	0.047	0.068	
b3	1.14	1.73	0.045	0.068	4
С	0.36	0.61	0.014	0.024	
c1	0.36	0.56	0.014	0.022	4
D	14.85	15.35	0.585	0.604	3
D1	8.38	9.02	0.330	0.355	

SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STNIBOL	MIN.	MAX.	MIN.	MAX.	NOTES
D2	11.68	13.30	0.460	0.524	6, 7
E	10.11	10.51	0.398	0.414	3, 6
E1	6.86	8.89	0.270	0.350	6
е	2.41	2.67	0.095	0.105	
e1	4.88	5.28	0.192	0.208	
H1	6.09	6.48	0.240	0.255	6
L	13.52	14.02	0.532	0.552	
L1	3.32	3.82	0.131	0.150	2
ØР	3.54	3.91	0.139	0.154	
Q	2.60	3.00	0.102	0.118	

Conforms to JEDEC<sup>®</sup> outline TO-220AC

#### Notes

- <sup>(1)</sup> Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Lead dimension and finish uncontrolled in L1
- (3) Dimension D, D1, and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (4) Dimension b1, b3, and c1 apply to base metal only
- <sup>(5)</sup> Controlling dimensions: inches
- <sup>(6)</sup> Thermal pad contour optional within dimensions E, H1, D2, and E1
- <sup>(7)</sup> Outline conforms to JEDEC<sup>®</sup> TO-220, except D2

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